

SANYO Semiconductors DATA SHEET

SBS817 — Low VF Schottky Barrier Diode 15V, 2.0A Rectifier

Applications

• High frequency rectification (switching regulators, converters, choppers).

Features

- Small switching noise.
- Low forward voltage- (IF=2.0A, VF max=0.46V)
- Ultrasmall package permitting applied sets to be small and slim (Mounting height 0.75mm).

Specifications

Absolute Maximum Ratings at Ta=25°C (Value per element)

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	VRRM		15	V
Nonrepetitive Peak Reverse Surge Voltage	VRSM		15	V
Average Output Current	IO		2.0	А
Surge Forward Current	IFSM	50Hz sine wave, 1 cycle	20	А
Junction Temperature	Tj		-55 to +125	°C
Storage Temperature	Tstg		-55 to +125	°C

Marking : SB

*: The absolute maximum ratings and electrical characteristics refer to those between Terminal 1 and Terminal 7 (or 8), and between Terminal 3 and Terminal 5 (or 6).

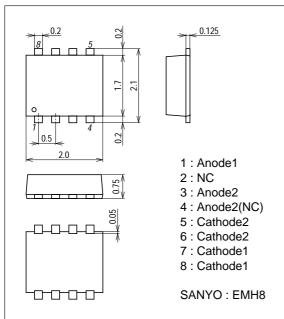
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Electrical Characteristics at Ta=25°C (Value per element)

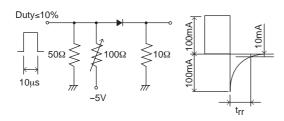
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Reverse Voltage	VR	IR=1mA	15			V
Forward Voltage	V _F 1	IF=1.0A		0.33	0.39	V
	V _F 2	IF=2.0A		0.39	0.46	V
Reverse Current	IR	V _R =7.5V			300	μΑ
Interterminal Capacitance	С	V _R =10V, f=1MHz		35		pF
Reverse Recovery Time	t _{rr}	IF=IR=100mA, See specified Test Circuit.			10	ns
Thermal Resistance	Rth(j-a)	When mounted on ceramic substrate (900mm ² ×0.8mm)		65		°C / W

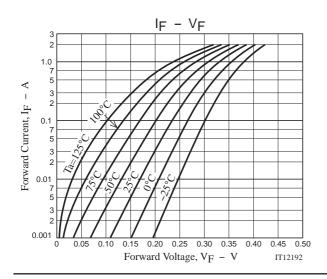
Package Dimensions



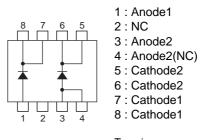


trr Test Circuit



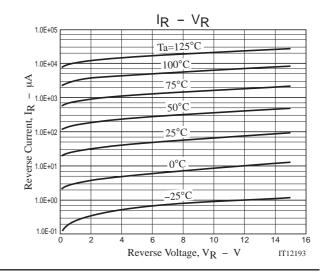


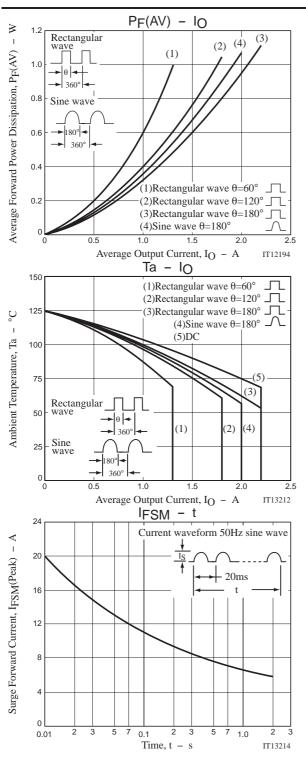
Electrical Connection

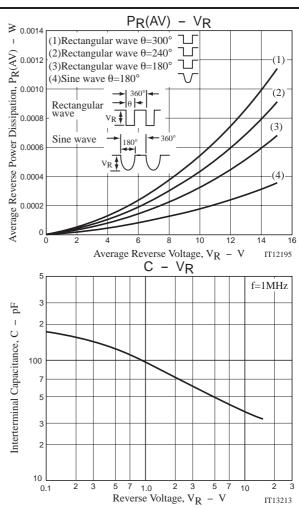


Top view

*: Terminal 4 is used for the purposes such as test. Although it is connected to Anode 2, please handle it as NC Terminal







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